

MOS FIELD EFFECT TRANSISTOR 3SK131

RF AMP. FOR VHF TV TUNER N-CHANNEL SILICON DUAL-GATE MOS FIELD-EFFECT TRANSISTOR 4PIN MINI MOLD

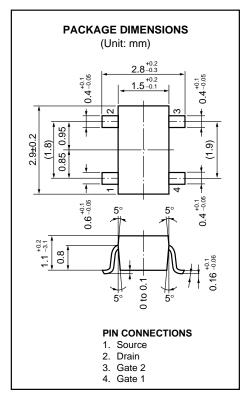
FEATURES

• Suitable for use as RF amplifier in VHF TV tuner.

Low C_{rss}: 0.05 pF TYP.
High G_{ps}: 23 dB TYP.
Low NF: 1.3 dB TYP.

ABSOLUTE MAXIMUM RATINGS (TA = 25 °C)

Drain to Source Voltage	VDSX	20	V
Gate1 to Source Voltage	V _{G1S}	±8	V
Gate2 to Source Voltage	V _{G2} S	±8	V
Drain Current	lσ	25	mΑ
Total Power Dissipation	Рт	200	mW
Channel Temperature	Tch	125	°C
Storage Temperature	Tstg	-55 to +125	°C

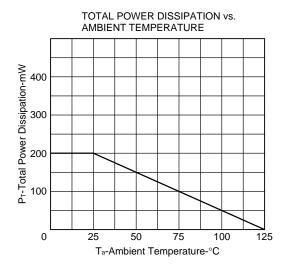


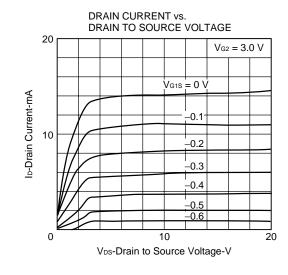
ELECTRICAL CHARACTERISTICS (TA = 25 °C)

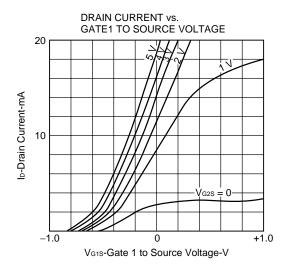
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain to Source Breakdown Voltage	BV _{DSX}	20			V	$V_{G1S} = V_{G2S} = -2 \text{ V}, \text{ ID} = 10 \mu\text{A}$
Drain Current	Ipss	7	10	25	mA	VDS = 6 V, VG2S = 3 V, VG1S = 0
Gate1 to Source Cutoff Voltage	V _{G1S(OFF)}			-2.0	V	$V_{DS} = 8 \text{ V}, V_{G2S} = 0, I_{D} = 5 \mu A$
Gate2 to Source Cutoff Voltage	V _{G2S(OFF)}			-1.5	V	$V_{DS} = 8 \text{ V } V_{G1S} = 0, \text{ ID} = 5 \mu A$
Gate1 Reverse Current	I _{G1SS}			±20	nA	$V_{DS} = 0$, $V_{G1S} = \pm 8 \text{ V}$, $V_{G2S} = 0$
Gate2 Reverse Current	I _{G2SS}			±20	nA	$V_{DS} = 0$, $V_{G2S} = \pm 8 \text{ V}$, $V_{G1S} = 0$
Forward Transfer Admittance	y _{fs}	22	28		mS	VDS = 6 V, VG2S = 3 V, ID = 10 mA
						f = 1 kHz
Input Capacitance	Ciss	4.0	5.0	6.5	pF	VDS = 6 V, VG2S = 3 V, ID = 10 mA
Output Capacitance	Coss	2.2	2.9	3.7	pF	f = 1 MHz
Reverse Transfer Capacitance	Crss		0.05	0.08	pF	
Power Gain	Cps	21	24		dB	V _{DS} = 10 V, V _{G2S} = 5 V, I _D = 10 mA
Noise Figure	NF		1.2	2.5	dB	f = 200 MHz

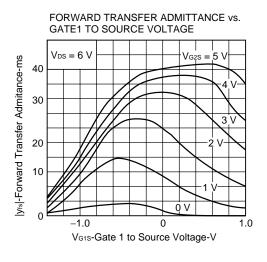


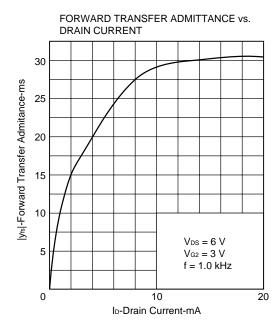
TYPICAL CHARACTERISTICS (TA = 25 °C)

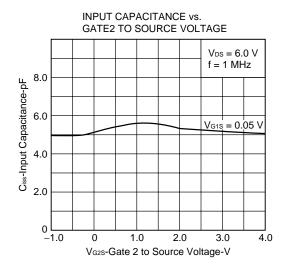




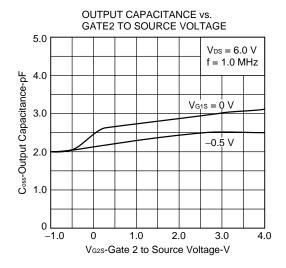


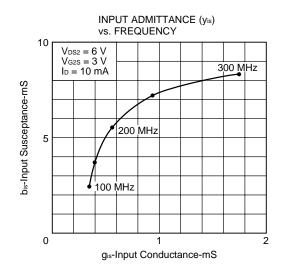


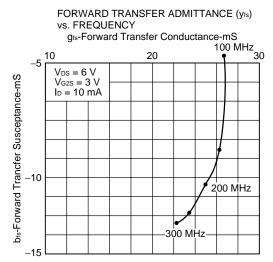


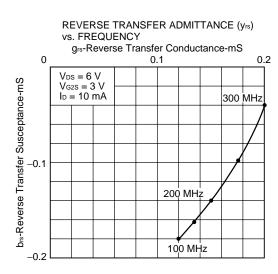


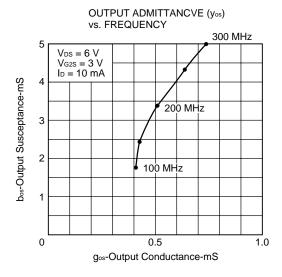


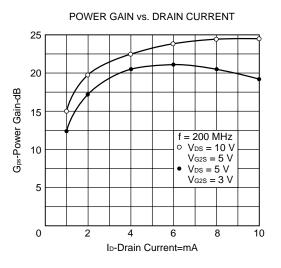






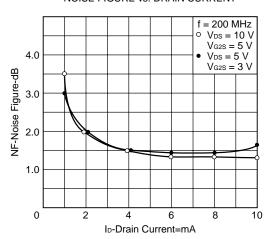




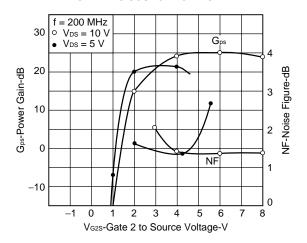


NEC

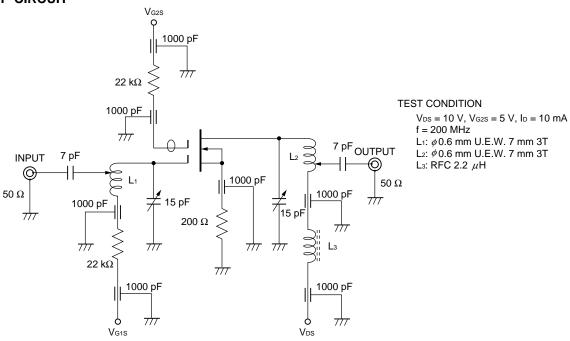
NOISE FIGURE vs. DRAIN CURRENT



NOISE FIGURE, POWER GAIN vs. GATE2 TO SOURCE VOLTAGE



TEST CIRCUIT



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Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)

Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

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Anti-radioactive design is not implemented in this product.

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